Power Transistor (-80V, -1A)

2SB1260 / 2SB1181 / 2SB1241

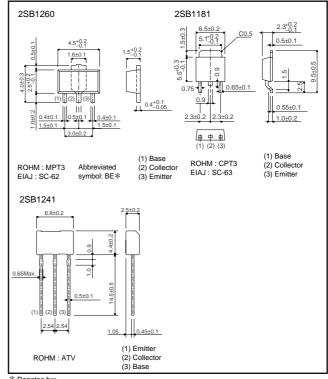
Features

- 1) Hight breakdown voltage and high current. BVceo=-80V, Ic = -1A
- 2) Good her linearty.
- 3) Low VCE(sat).
- 4) Complements the 2SD1898 / 2SD1863 / 2SD1733.

Structure

Epitaxial planar type PNP silicon transistor

●External dimensions (Unit : mm)



* Denotes her

● Absolute maximum ratings (Ta=25°C)

Parameter		Symbol	Limits	Unit	
Collector-base voltage		Vсво	-80	V	
Collector-emitter voltage		Vceo	-80	V	
Emitter-base voltage		Vево	-5	V	
Collector current		Ic	-1	A (DC)	
		ICP	-2 *1	A (Pulse)	
	2SB1260		0.5	W	
Collector power dissipation		_ [2 *2		
	2SB1241, 2SB1181	Pc	1 *3		
	2SB1181		10	W (Tc=25°C)	
Junction temperature		Tj	150	°C	
Storage temperature		Tstg	-55 to 150	°C	

*1 2SB1260 : Pw=20ms duty=1/2

2SB1241 : Single pulse, Pw=100ms

\$2 2SB1260 : When mounted on a 40×40×0.7 mm ceramic board.

 ${\rm *3\ 2SB1241:Printed\ circuit\ board,\ 1.7mm\ thick,\ collector\ copper\ plating\ 100mm^2\ or\ larger.}$

●Electrical characteristics (Ta=25°C)

Parameter		Symbol	Min.	Тур.	Max.	Unit	Conditions	
Collector-base breakdown voltage		ВУсво	-80	-	_	V	Ic= -50μA	
Collector-emitter breakdown voltage		BVceo	-80	-	_	V	Ic=-1mA	
Emitter-base breakdown voltage		ВVево	-5	-	_	V	IE= -50μA	
Collector cutoff current		Ісво	_	_	-1	μΑ	Vcb= -60V	
Emitter cutoff current		ІЕВО	_	-	-1	μΑ	V _{EB} = -4V	
Collector-emitter saturation voltage		VCE(sat)	_	_	-0.4	V	Ic/I _B = -500mA/ -50mA	
DC current transfer ratio	2SB1260, 2SB1181	hfe	82	-	390	_	Vce= -3V, lc= -0.1A	
	2SB1241	IIFE	120	-	390	_		
Transition frequency	2SB1181	f⊤	_	100	_	MHz	Vce= -10V, Ie=50mA, f=100MHz	
Output capacitance	2SB1260	Cob	_	20	_	pF	V _{CB} = -10V	
	2SB1181, 2SB1241	COD	_	25	_	pF	le=0A f=1MHz	

●Packaging specifications and hFE

		Package	Taping		
		Code	TL	TV2	T100
Туре	hfe	Basic ordering unit (pieces)	2500	2500	1000
2SB1260	PQR		_	-	0
2SB1241	QR		_	0	_
2SB1181	PQR		0	-	_

hre values are classified as follows:

Item	Р	Q	R
hfE	82 to 180	120 to 270	180 to 390

•Electrical characteristic curves

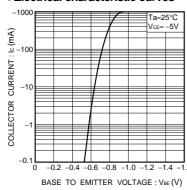


Fig.1 Grounded emitter propagation characteristics

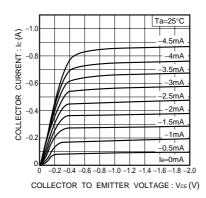


Fig.2 Grounded emitter output characteristics

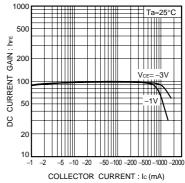
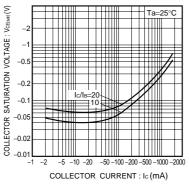
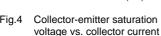


Fig.3 DC current gain vs. collector current





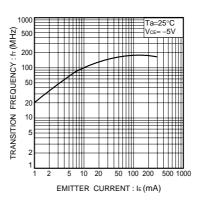


Fig.5 Gain bandwidth product vs. emitter current

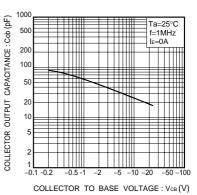


Fig.6 Collector output capacitance vs. collector-base voltage

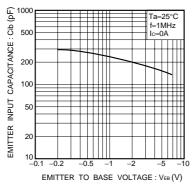


Fig. 7 Emitter input capacitance vs. emitter-base voltage

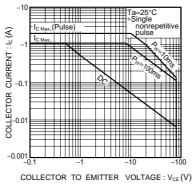


Fig.8 Safe operating area (2SB1260)

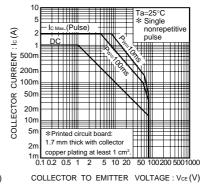


Fig.9 Safe operating area (2SB1241)

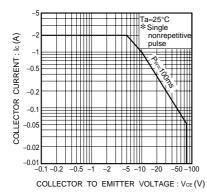


Fig.10 Safe operating area (2SB1181)

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